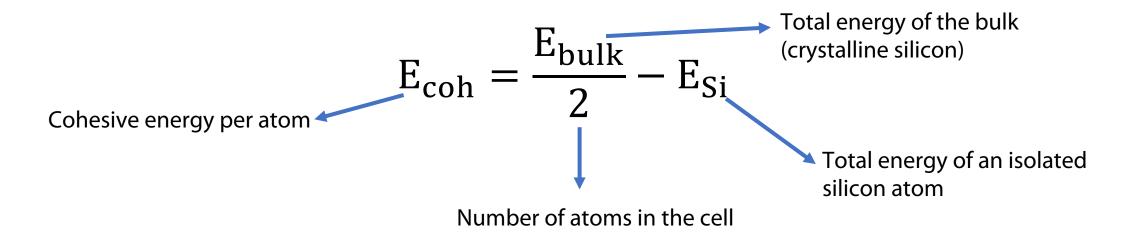
Cohesive energy

- The cohesive energy is defined as the heat of sublimation of a solid into its elements.
- In practice, you need to calculate difference between the total energy at the equilibrium lattice parameter and the total energy of each isolated atom



The experimentally measured cohesive energy for silicon is ~4.6 eV.

Input files available at https://github.com/AntimoMarrazzo/DFT_course_UniTS/tree/main/cohesive

The isolated atom

```
&SYSTEM
                                                                      Cubic cell
   ibrav
   celldm(1)
                      = 30
                                                                      30 Bohr
                      = 40.0
   ecutwfc
   ntyp
   nat
                                                                   Spin-polarized calculations
   nspin
                         'smearing'
   occupations
   degauss = 0.01
   tot_magnetization = 2 ◆
                                    We impose the total magnetization to be equal to 2 (Bohr magnetons)
   nbnd = 5
&ELECTRONS
                      = 1.d-12
   conv_thr
                                                              Silicon outer shell is 3p and follows
                                                                       Hund's rules
ATOMIC_SPECIES
Si 28.086 Si.pbe_PseudoDojo.UPF
K_POINTS gamma
ATOMIC_POSITIONS alat
    0.000000000 0.000000000 0.000000000
```

Exercise & Homework

- **Exercise to do now**: converge the cohesive energy w.r.t to the wavefunction cutoffs. Does it converge faster than the total energy of the bulk?
- Homework: Calculate the cohesive energy of diamond and compare with its experimental value (~7.4 eV)

Electronic temperature (smearing)

Why do we introduce smearing?

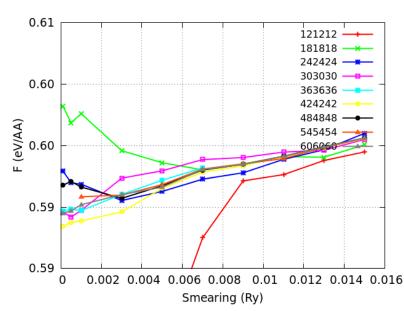
To improve the convergence with respect to Brillouin zone sampling in metals (also to improve convergence with level crossing instabilities in the SCF)

Why does it work?:

It **smoothens the discontinuous occupation function**, so k-space integrals can be integrated with higher accuracy at lower computational cost

• Side effects: you integrate the **wrong energy functional** E-TS (where T can be thousands of Kelvin), hence introducing a **systematic error**

- How to choose the temperature (and k-point sampling):
 - 1. decide what is the tolerated error (e.g. on the forces)
 - choose a smearing such that the error is within tolerance
 - 3. For that smearing choose the smallest k-point sampling that correctly integrates the Brillouin zone.



SCF and bands of bulk nickel

- Run a SCF and band-structure calculation for magnetic nickel:
 - 1. SCF
 - 2. Bands
 - 3. Bands postprocessing: run twice, one for spin-up and one for spin-down bands.
 - 4. Plot spin-up and spin-down bands with gnuplot



Input files available at https://github.com/AntimoMarrazzo/DFT_course_UniTS/tree/main/ni